

# **Maximum Ratings** @T<sub>A</sub> = 25°C unless otherwise specified

| Characteristic       |                      | Symbol           | Value      | Units |
|----------------------|----------------------|------------------|------------|-------|
| Drain-Source Voltage |                      | V <sub>DSS</sub> | 30         | V     |
| Gate-Source Voltage  | Continuous           | V <sub>GSS</sub> | ±20        | V     |
| Drain Current        | Continuous<br>Pulsed | I <sub>D</sub>   | 1.1<br>4.0 | A     |

## Thermal Characteristics @TA = 25°C unless otherwise specified

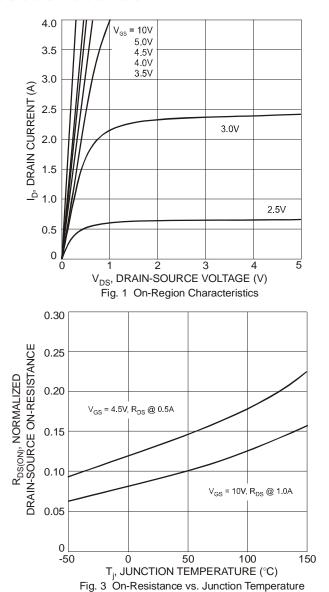
| Characteristic                          | Symbol                            | Value       | Units |
|---|-----------------------------------|-------------|-------|
| Total Power Dissipation                 | $P_{D}$                           | 500         | mW    |
| Thermal Resistance, Junction to Ambient | $R_{	heta JA}$                    | 250         | K/W   |
| Operating and Storage Temperature Range | T <sub>J</sub> , T <sub>STG</sub> | -55 to +150 | °C    |

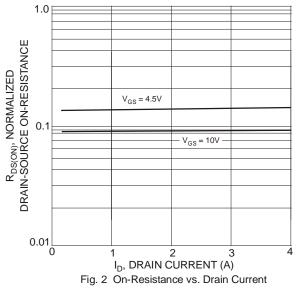
# Electrical Characteristics @T<sub>A</sub> = 25°C unless otherwise specified

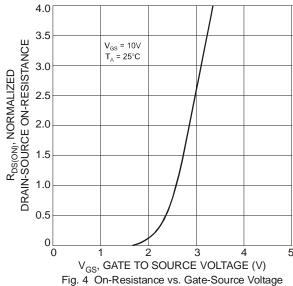
| Characteristic                    |   | Symbol               | Min | Тур | Max            | Unit | Test Condition   |  |
|-----------------------------------|---|----------------------|-----|-----|----------------|------|--|--|
| OFF CHARACTERISTICS (Note 4)      |   |                      |     |     |                |      |  |  |
| Drain-Source Breakdown Voltage    |   | BV <sub>DSS</sub>    | 30  | _   | _              | V    | $V_{GS} = 0V, I_D = 250 \mu A$                                     |  |
| Zero Gate Voltage Drain Current   | @ $T_J = 25^{\circ}C$<br>@ $T_J = 125^{\circ}C$ | I <sub>DSS</sub>     | _   | _   | 1.0<br>10      | μА   | V <sub>DS</sub> = 24V, V <sub>GS</sub> = 0V                        |  |
| Gate-Body Leakage                 |   | I <sub>GSS</sub>     | _   | _   | ± 100          | nA   | $V_{GS} = \pm 12V, V_{DS} = 0V$                                    |  |
| ON CHARACTERISTICS (Note 4)       |   |                      |     |     |                |      |  |  |
| Gate Threshold Voltage            |   | $V_{GS(th)}$         | 1.0 | _   | 3.0            | V    | $V_{DS} = 10V, I_{D} = 1.0 \text{mA}$                              |  |
| Static Drain-Source On-Resistance |   | R <sub>DS (ON)</sub> | _   | _   | 0.170<br>0.150 | Ω    | $V_{GS} = 4.5V, I_D = 0.5A$<br>$V_{GS} = 10V, I_D = 1.0A$          |  |
| Forward Transconductance          |   | <b>g</b> FS          | 1.3 | 2.4 |                | S    | $V_{DS} = 10V, I_{D} = 0.5A$                                       |  |
| DYNAMIC CHARACTERISTICS           |   |                      |     |     |                |      |  |  |
| Input Capacitance                 |   | C <sub>iss</sub>     | _   | 150 | _              | pF   | 1/ 10)/ )/ 0)/   |  |
| Output Capacitance                |   | Coss                 | _   | 90  |                | pF   | $V_{DS} = 10V, V_{GS} = 0V$<br>- f = 1.0MHz                        |  |
| Reverse Transfer Capacitance      |   | Crss                 | _   | 30  | _              | pF   |  |  |
| Total Gate Charge                 |   | $Q_g$                | _   | 5.5 | _              | nC   | $V_{DS} = 24V, I_D = 1.0A,$  |  |
| Gate-to-Source Charge             |   | Qgs                  | _   | 8.0 | _              | nC   |  |  |
| Gate-to-Drain Charge              |   | $Q_{gd}$             | _   | 1.3 | _              | nC   | V <sub>GS</sub> = 10V  |  |
| SWITCHING CHARACTERISTICS         |   |                      |     |     |                |      |  |  |
| Turn-On Delay Time                |   | t <sub>D(ON)</sub>   | _   | 10  | _              | ns   |  |  |
| Turn-Off Delay Time               |   | t <sub>D(OFF)</sub>  | _   | 25  |                | ns   | $V_{DD} = 10V, I_D = 0.5A,$<br>$V_{GS} = 5.0V, R_{GEN} = 50\Omega$ |  |
| Turn-On Rise Time                 |   | t <sub>r</sub>       | _   | 15  | _              | ns   |  |  |
| Turn-Off Fall Time                |   | t <sub>f</sub>       | _   | 45  | _              | ns   |  |  |
| SOURCE-DRAIN RATINGS (BODY DIODE) |   |                      |     |     |                |      |  |  |
| Continuous Source Current         |   | Is                   | _   | _   | 0.54           | Α    | _  |  |
| Pulse Source Current              |   | I <sub>SM</sub>      | _   | _   | 4.0            | Α    |  |  |
| Forward Voltage                   |   | $V_{SD}$             |     |     | 1.2            | V    | $I_F = 1.0A, V_{GS} = 0V$  |  |
| Reverse Recovery Time             |   | t <sub>rr</sub>      |     | 35  | _              | ns   | $I_F = 1.0A$ , $di/dt = 50A/\mu s$                                 |  |

Notes: 4. Pulse width  $\leq 300 \mu s, \ duty \ cycle \leq 2\%.$ 

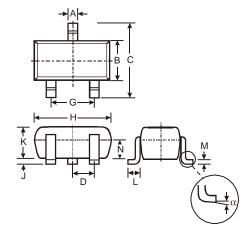








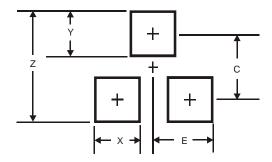
# **Package Outline Dimensions**



| SC59                 |       |      |      |  |  |  |
|----------------------|-------|------|------|--|--|--|
| Dim                  | Min   | Max  | Тур  |  |  |  |
| Α                    | 0.35  | 0.50 | 0.38 |  |  |  |
| В                    | 1.50  | 1.70 | 1.60 |  |  |  |
| C                    | 2.70  | 3.00 | 2.80 |  |  |  |
| D                    | -     | -    | 0.95 |  |  |  |
| G                    | -     | -    | 1.90 |  |  |  |
| Н                    | 2.90  | 3.10 | 3.00 |  |  |  |
| J                    | 0.013 | 0.10 | 0.05 |  |  |  |
| K                    | 1.00  | 1.30 | 1.10 |  |  |  |
| L                    | 0.35  | 0.55 | 0.40 |  |  |  |
| M                    | 0.10  | 0.20 | 0.15 |  |  |  |
| N                    | 0.70  | 0.80 | 0.75 |  |  |  |
| α                    | 0°    | 8°   | -    |  |  |  |
| All Dimensions in mm |       |      |      |  |  |  |



## Suggested Pad Layout



| Dimensions | Value (in mm) |
|------------|---------------|
| Z          | 3.4           |
| Х          | 0.8           |
| Υ          | 1.0           |
| С          | 2.4           |
| E          | 1.35          |

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